

# SiC Schottky Barrier Diode

$V_R$	1200V		
l <sub>F</sub>	5A		
$Q_C$	20nC		

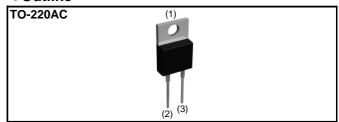
### Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

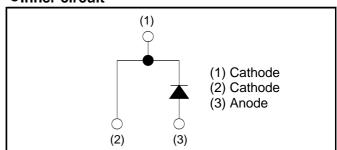
## Construction

Silicon carbide epitaxial planer type

## Outline



## •Inner circuit



Packaging specifications

	<del></del>		
Type	Packaging	Tube	
	Reel size (mm)	-	
	Tape width (mm)	-	
	Basic ordering unit (pcs)	50	
	Taping code	-	
	Marking	SCS105KG	

#### ● Absolute maximum ratings (Ti = 25°C)

Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)	$V_{RM}$	1200	V
Reverse voltage (DC)	V <sub>R</sub>	1200	V
Continuous forward current	I <sub>F</sub>	5* <sup>1</sup>	А
Curso no repetitive forward current	1	21* <sup>2</sup>	А
Surge no repetitive forward current	I <sub>FSM</sub>	97* <sup>3</sup>	А
Repetitive peak forward current	I <sub>FRM</sub>	24* <sup>4</sup>	А
Total power dissipation	P <sub>D</sub>	83* <sup>5</sup>	W
Junction temperature	Tj	175	°C
Range of storage temperature	Tstg	-55 to +175	°C
Thermal resistance, junction to case	Rth(j-c)	1.8	°C/W

<sup>\*1</sup> Tc=148°C \*2 PW=8.3ms sinusoidal,Tj=25°C

# ●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter			Min.	Тур.	Max.	Unit
DC blocking voltage	$V_{DC}$	I <sub>R</sub> =0.1mA	1200	-	-	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =5A,Tj=25°C	-	1.5	1.75	V
		I <sub>F</sub> =5A,Tj=175°C	-	2.0	-	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1200V,Tj=25°C	-	5	100	μΑ
		V <sub>R</sub> =1200V,Tj=175°C	-	60	-	μΑ
Total capacitance	С	V <sub>R</sub> =1V,f=1MHz	-	325	-	pF
		V <sub>R</sub> =800V,f=1MHz	-	25	-	pF
Total capacitive charge	Qc	V <sub>R</sub> =800V,di/dt=500A/μs	-	20	-	nC
Switching time	tc	V <sub>R</sub> =800V,di/dt=500A/μs	ı	15	-	ns

## •Electrical characteristic curves

F: 41/4 | Ol | | | | | |

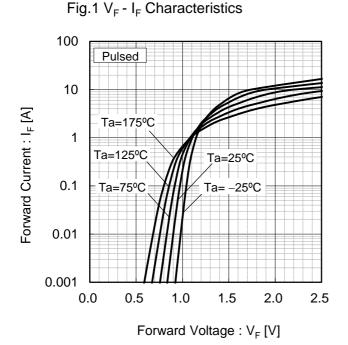
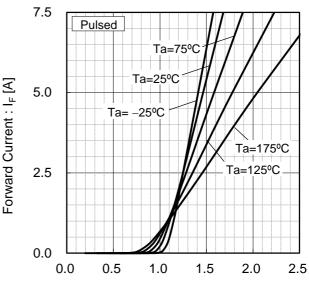


Fig.2 V<sub>F</sub> - I<sub>F</sub> Characteristics



Forward Voltage : V<sub>F</sub> [V]

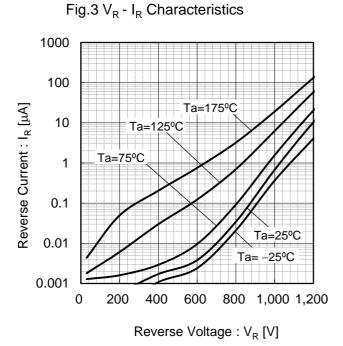
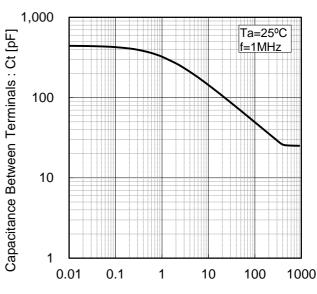


Fig.4 V<sub>R</sub>-Ct Characteristics



Reverse Voltage : V<sub>R</sub> [V]

## •Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width

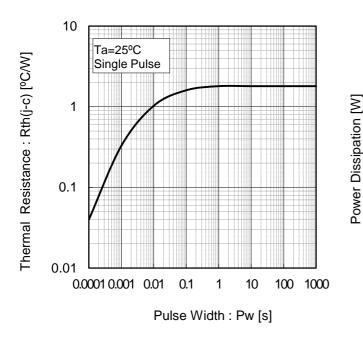
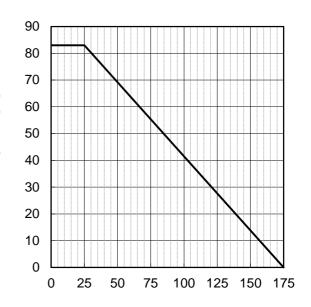


Fig.6 Power Dissipation



Case Temperature: Tc [°C]

Fig.7 Derating Curve Ip-Tc

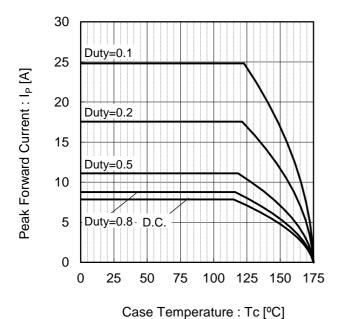
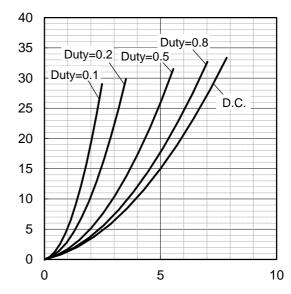


Fig.8 Io-Pf Characteristics

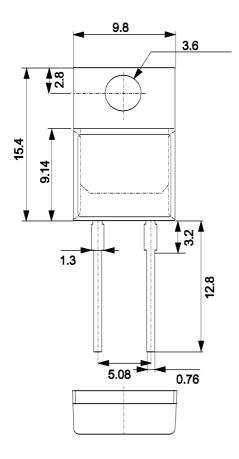


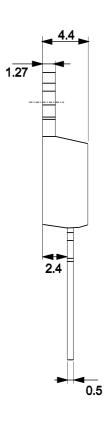
Average Rectified Forward Current : Io [A]

Power Dissipation [W]

●Dimensions (Unit:mm)

## **TO-220AC**





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